



АС ЭНЕРГИЯ

Тиристорный модуль АМКТ 105



V_{RSM} V	V_{RRM}, V_{DRM} V	$I_{TRMS} = 180$ A (maximum value for continuous operation) $I_{TAV} = 106$ A (sin 180; $T_c = 85$ °C)	
500	400	–	AMKH 105-04D
700	600	AMKT 105-06E	AMKH 105-06D
900	800	AMKT 105-08E	AMKH 105-08D
1300	1200	AMKT 105-12E	AMKH 105-12E
1500	1400	AMKT 105-14E	AMKH 105-14E
1700	1600	AMKT 105-16E	AMKH 105-16E
1900	1800	AMKT 105-18E	AMKH 105-18E

Symbol	Conditions	Values	Units
I_{TAV}	sin. 180; $T_c = 85$ (100) °C;	106 (78)	A
I_D	P3/180F; $T_a = 35$ °C; B2 / B6	145 / 180	A
	P16/200F; $T_a = 35$ °C; B2 / B6	190 / 260	A
I_{RMS}	P3/180F; $T_a = 35$ °C; W1 / W3	200 / 3 * 140	A
I_{TSM}	$T_{vj} = 25$ °C; 10 ms	2250	A
	$T_{vj} = 130$ °C; 10 ms	1900	A
i^2t	$T_{vj} = 25$ °C; 8,3 ... 10 ms	25000	A ² s
	$T_{vj} = 130$ °C; 8,3 ... 10 ms	18000	A ² s
V_T	$T_{vj} = 25$ °C; $I_T = 300$ A	max. 1,65	V
$V_{T(TO)}$	$T_{vj} = 130$ °C	max. 0,9	V
r_T	$T_{vj} = 130$ °C	max. 2	mΩ
$I_{DD}; I_{RD}$	$T_{vj} = 130$ °C; $V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$	max. 20	mA
t_{gd}	$T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs	1	μs
t_{gr}	$V_D = 0,67 * V_{DRM}$	2	μs
$(di/dt)_{cr}$	$T_{vj} = 130$ °C	max. 150	A/μs
$(dv/dt)_{cr}$	$T_{vj} = 130$ °C ;	max. 500 / 1000	V/μs
t_q	$T_{vj} = 130$ °C ,	100	μs
I_H	$T_{vj} = 25$ °C; typ. / max.	150 / 250	mA
I_L	$T_{vj} = 25$ °C; $R_G = 33$ Ω; typ. / max.	300 / 600	mA
V_{GT}	$T_{vj} = 25$ °C; d.c.	min. 3	V
I_{GT}	$T_{vj} = 25$ °C; d.c.	min. 150	mA
V_{GD}	$T_{vj} = 130$ °C; d.c.	max. 0,25	V
I_{GD}	$T_{vj} = 130$ °C; d.c.	max. 6	mA
$R_{th(j-c)}$	cont.; per thyristor / per module	0,28 / 0,14	K/W
$R_{th(j-c)}$	sin. 180; per thyristor / per module	0,3 / 0,15	K/W
$R_{th(j-c)}$	rec.120; per thyristor / per module	0,32 / 0,16	K/W
$R_{th(c-s)}$	per thyristor / per module	0,2 / 0,1	K/W
T_{vj}		- 40 ... + 130	°C
T_{stg}		- 40 ... + 125	°C
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 / 3000	V~
M_s	to heatsink	5 ± 15 % ¹⁾	Nm
M_t	to terminals	5 ± 15%	Nm
a		5 * 9,81	m/s ²
m	approx.	95	g

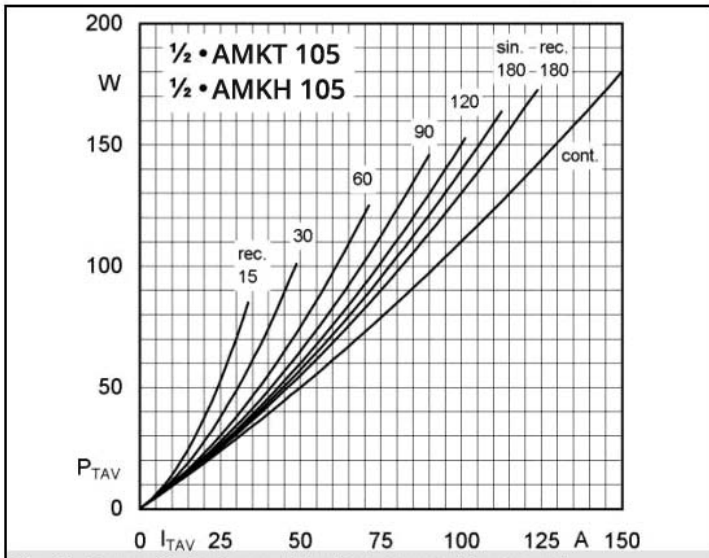


Fig. 1L Power dissipation per thyristor vs. on-state current

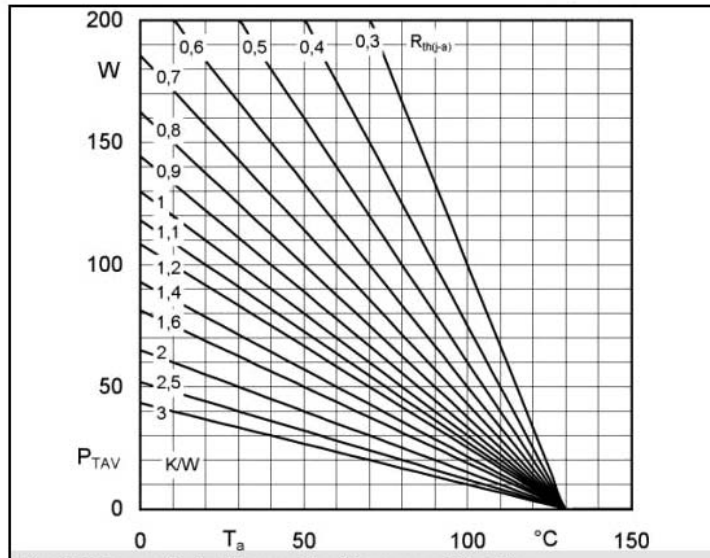


Fig. 1R Power dissipation per thyristor vs. ambient temp.

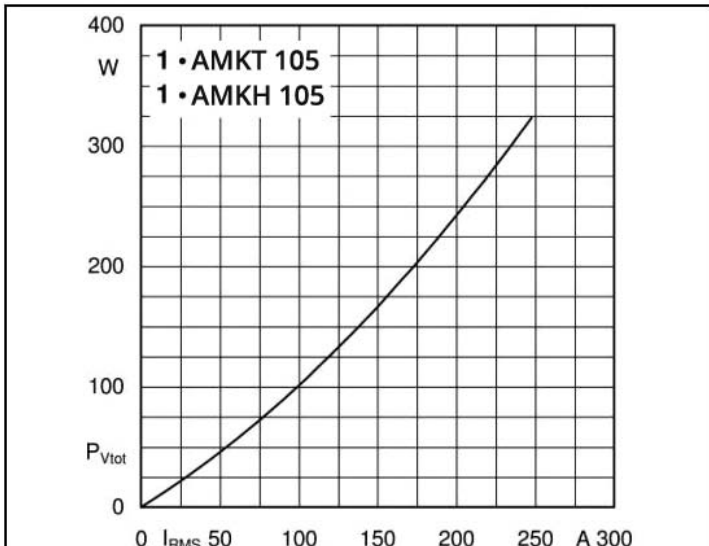


Fig. 2L Power dissipation per module vs. rms current

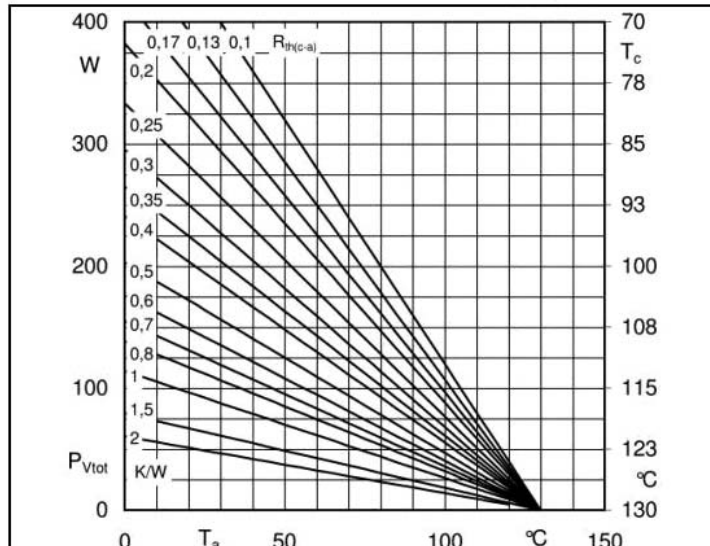


Fig. 2R Power dissipation per module vs. case temp.

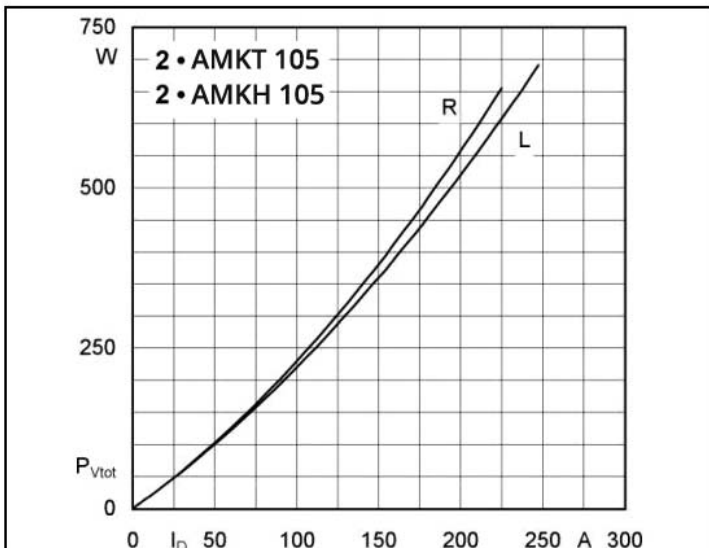


Fig. 3L Power dissipation of two modules vs. direct current

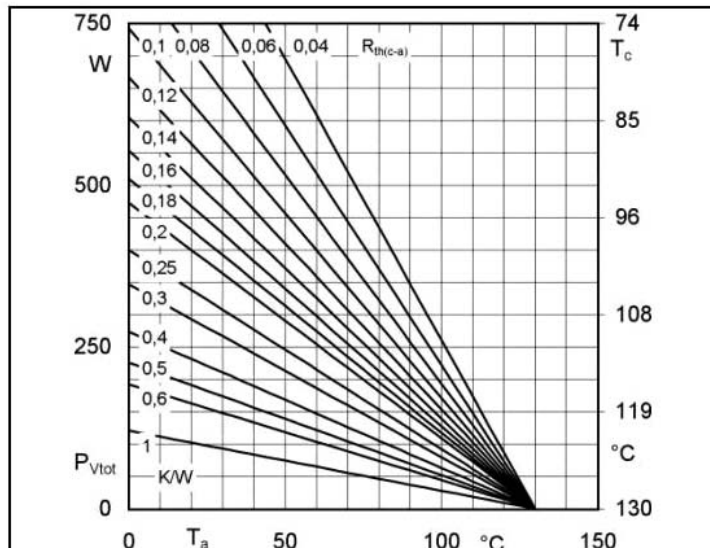
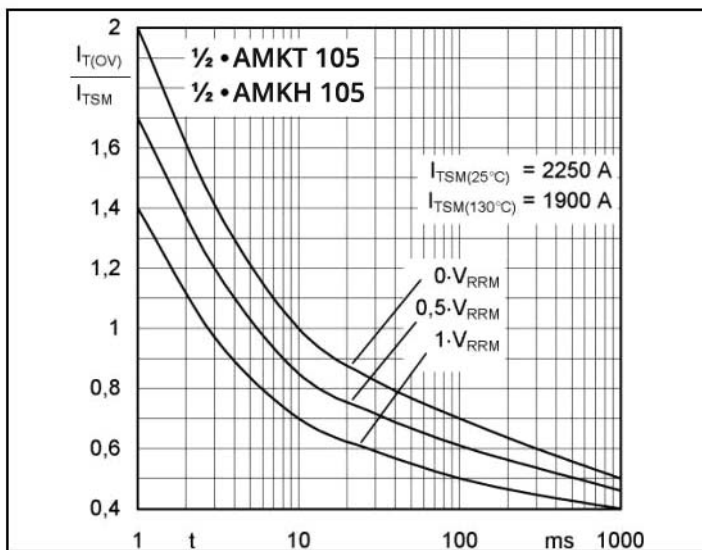
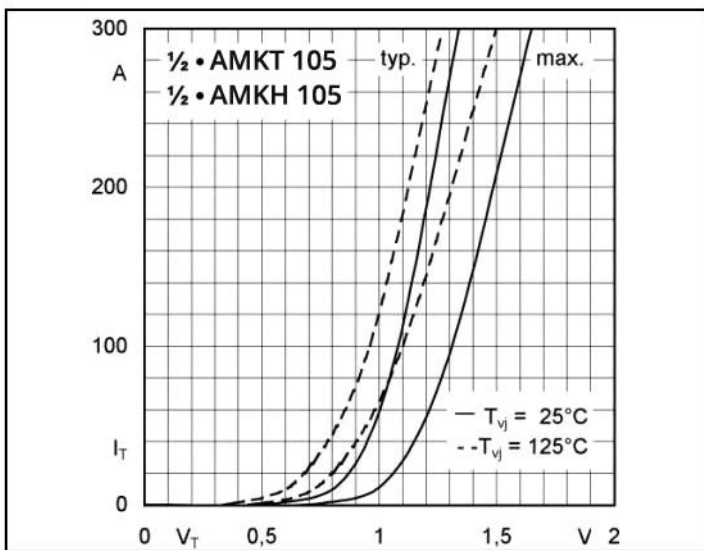
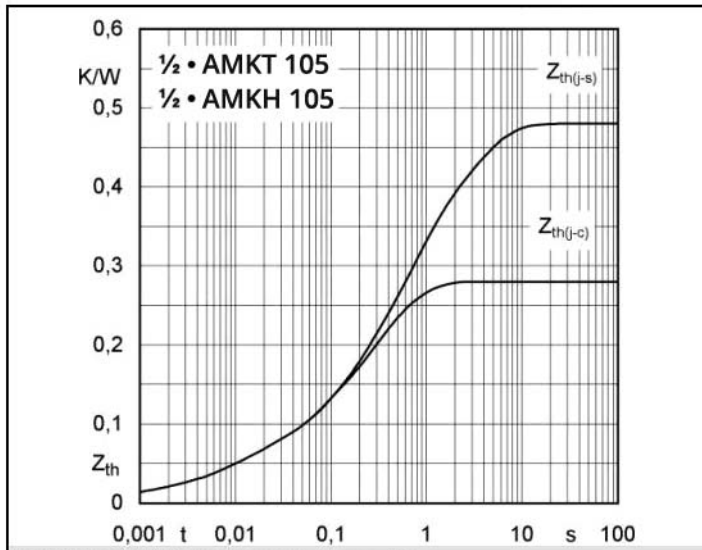
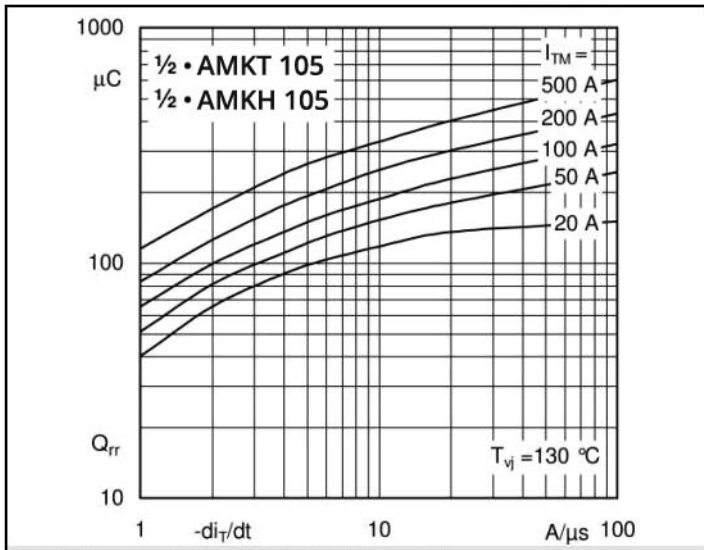
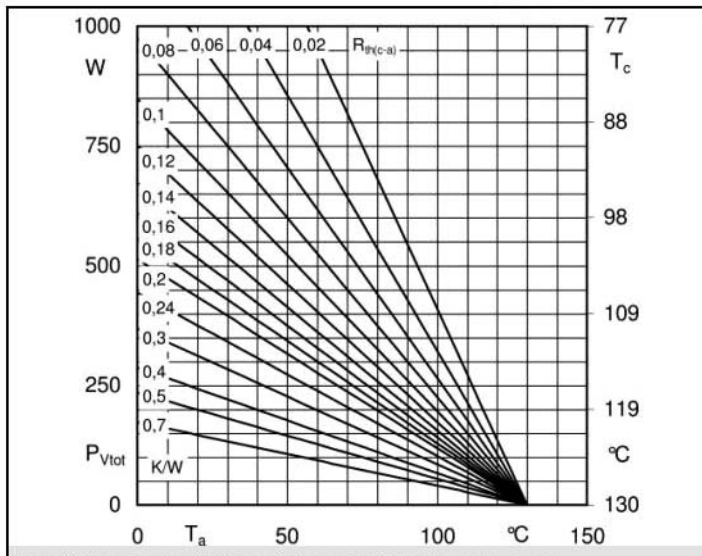
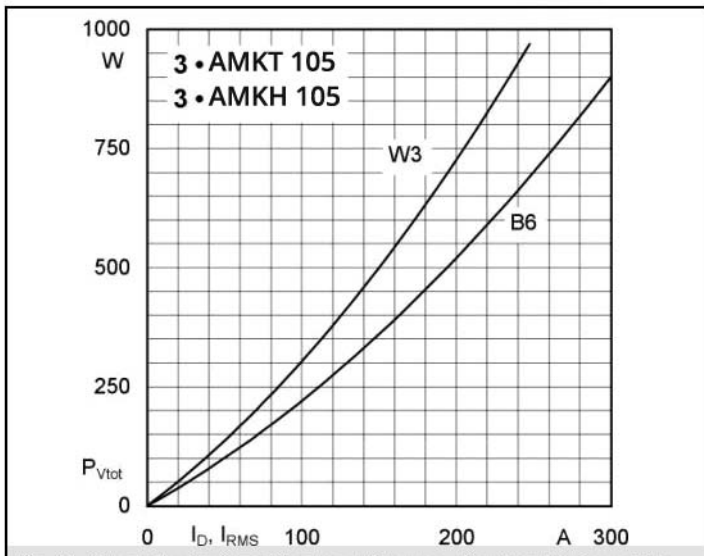
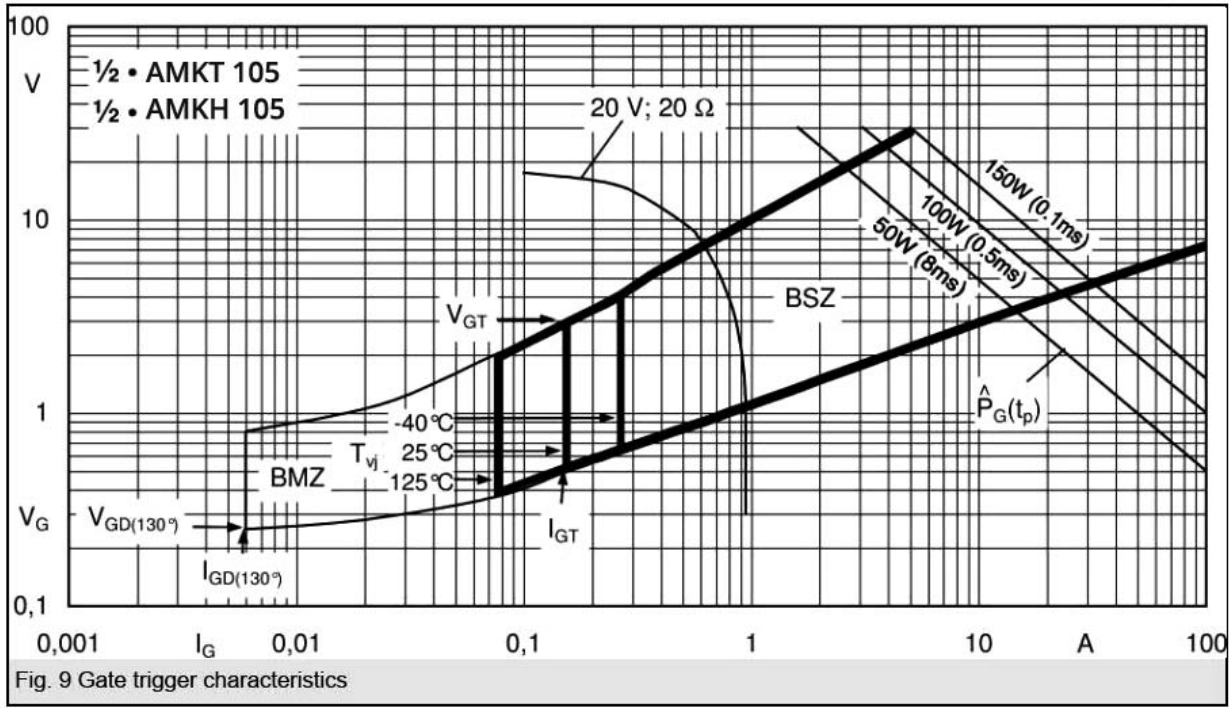


Fig. 3R Power dissipation of two modules vs. case temp.

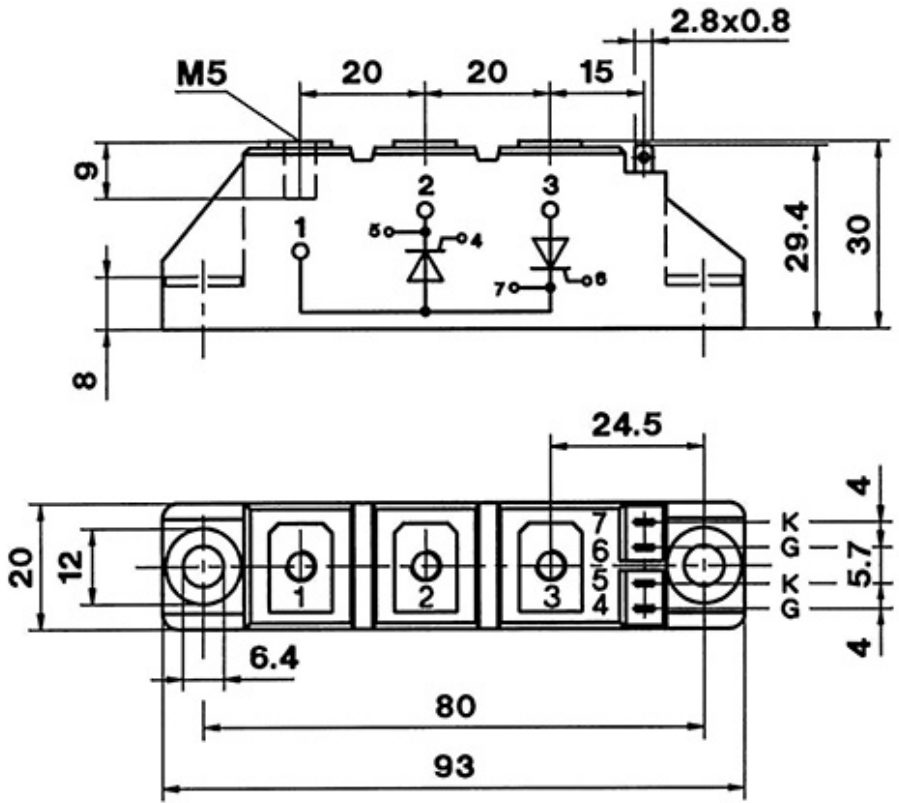




DIMENSIONS

AMKT

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Dimensions in mm

TOPOLOGY OF INTERNAL CONNECTION



AMKT

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